# MMBT6520L, NSVMMBT6520L

# High Voltage Transistor PNP Silicon

### Features

- NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

### MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector – Emitter Voltage	V <sub>CEO</sub>	-350	Vdc
Collector – Base Voltage	V <sub>CBO</sub>	-350	Vdc
Emitter-Base Voltage	V <sub>EBO</sub>	-5.0	Vdc
Base Current	Ι <sub>Β</sub>	-250	mA
Collector Current – Continuous	Ι <sub>C</sub>	-500	mAdc

#### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR–5 Board, (Note 1) T <sub>A</sub> = 25°C Derate above 25°C	P <sub>D</sub>	225 1.8	mW mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	556	°C/W
Total Device Dissipation Alumina Substrate, (Note 2) T <sub>A</sub> = 25°C Derate above 25°C	PD	300 2.4	mW mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	417	°C/W
Junction and Storage Temperature	T <sub>J</sub> , T <sub>stg</sub>	–55 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

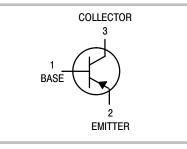
1. FR-5 =  $1.0 \times 0.75 \times 0.062$  in.

2. Alumina = 0.4 x 0.3 x 0.024 in. 99.5% alumina.



## **ON Semiconductor®**

#### http://onsemi.com





### MARKING DIAGRAM



2Z = Device Code

M = Date Code\*

= Pb-Free Package

(Note: Microdot may be in either location) \*Date Code orientation and/or overbar may vary depending upon manufacturing location.

### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
MMBT6520LT1G	SOT-23 (Pb-Free)	3000 / Tape & Reel
MMBT6520LT3G	SOT-23 (Pb-Free)	10,000 / Tape & Reel
NSVMMBT6520LT1G	SOT-23 (Pb-Free)	3,000 / Tape & Reel

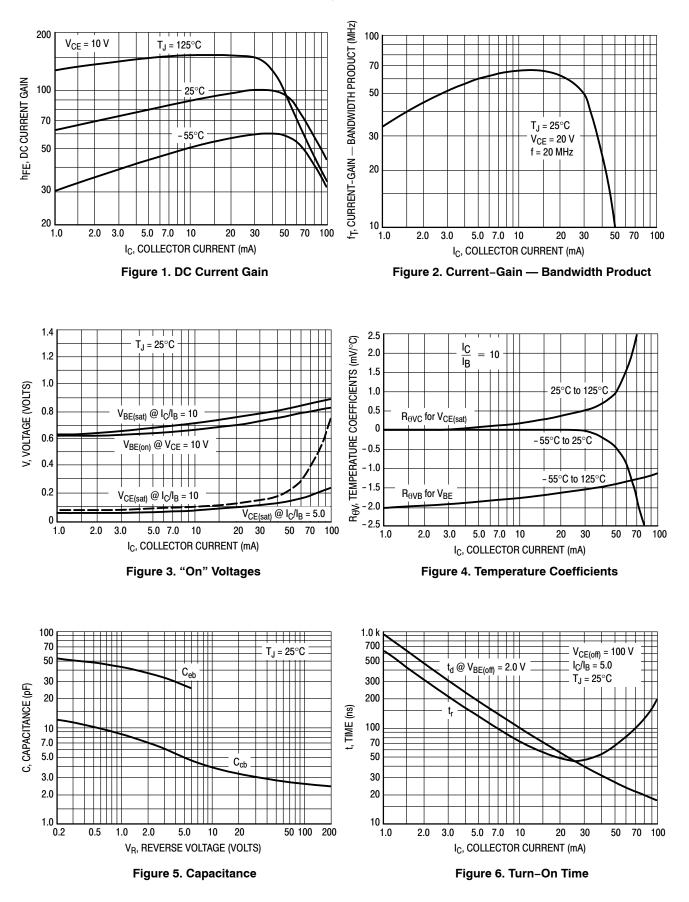
†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

## MMBT6520L, NSVMMBT6520L

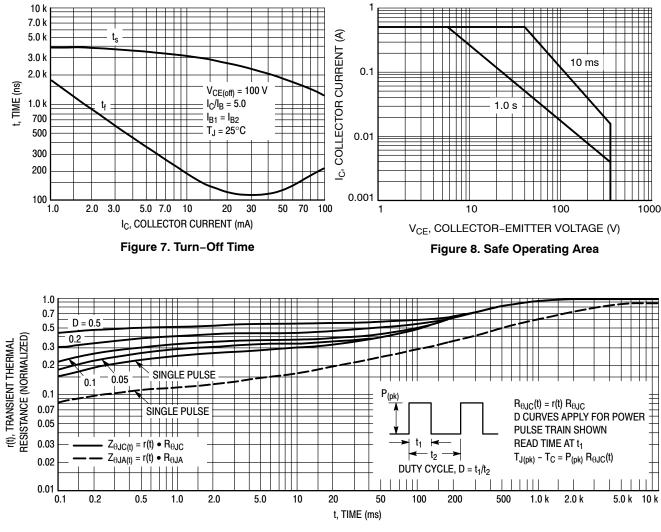
### **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				•
Collector–Emitter Breakdown Voltage $(I_{C} = -1.0 \text{ mA})$	V <sub>(BR)CEO</sub>	-350	-	Vdc
Collector–Base Breakdown Voltage $(I_C = -100 \ \mu A)$	V <sub>(BR)CBO</sub>	-350	_	Vdc
Emitter–Base Breakdown Voltage (I <sub>E</sub> = −10 μA)	V <sub>(BR)EBO</sub>	-5.0	_	Vdc
Collector Cutoff Current $(V_{CB} = -250 \text{ V})$	I <sub>CBO</sub>	_	-50	nA
Emitter Cutoff Current (V <sub>EB</sub> = -4.0 V)	I <sub>EBO</sub>	-	-50	nA
ON CHARACTERISTICS				
DC Current Gain	h <sub>FE</sub>	20 30 30 20 15	_ 200 200 _	_
	V <sub>CE(sat)</sub>	- - - -	-0.30 -0.35 -0.50 -1.0	Vdc
$\begin{array}{l} \text{Base-Emitter Saturation Voltage} \\ (I_{C} = -10 \text{ mA}, I_{B} = -1.0 \text{ mA}) \\ (I_{C} = -20 \text{ mA}, I_{B} = -2.0 \text{ mA}) \\ (I_{C} = -30 \text{ mA}, I_{B} = -3.0 \text{ mA}) \end{array}$	V <sub>BE(sat)</sub>		-0.75 -0.85 -0.90	Vdc
Base–Emitter On Voltage ( $I_C = -100$ mA, $V_{CE} = -10$ V)	V <sub>BE(on)</sub>	_	-2.0	Vdc
SMALL-SIGNAL CHARACTERISTICS				
Current–Gain – Bandwidth Product ( $I_C = -10 \text{ mA}, V_{CE} = -20 \text{ V}, f = 20 \text{ MHz}$ )	f <sub>T</sub>	40	200	MHz
Collector-Base Capacitance $(V_{CB}=-20 \text{ V}, \text{ f}=1.0 \text{ MHz})$	C <sub>cb</sub>	_	6.0	pF
Emitter-Base Capacitance (V <sub>EB</sub> = -0.5 V, f = 1.0 MHz)	C <sub>eb</sub>	-	100	pF

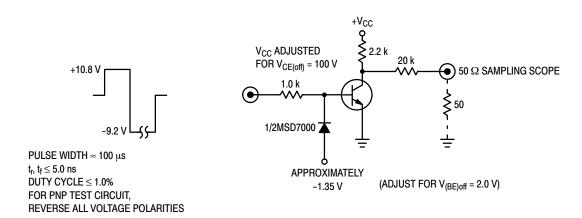
### MMBT6520L, NSVMMBT6520L



### MMBT6520L, NSVMMBT6520L



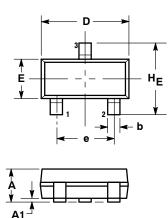


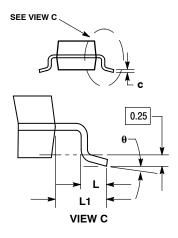




#### PACKAGE DIMENSIONS

SOT-23 (TO-236) CASE 318-08 ISSUE AP





NOTES:

DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
CONTROLLING DIMENSION: INCH.

2. CONTROLLING DIMENSION: INCH. 3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH

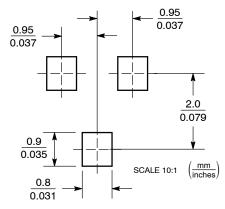
THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.

4. DIMENSIONS D'AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.89	1.00	1.11	0.035	0.040	0.044
A1	0.01	0.06	0.10	0.001	0.002	0.004
b	0.37	0.44	0.50	0.015	0.018	0.020
c	0.09	0.13	0.18	0.003	0.005	0.007
D	2.80	2.90	3.04	0.110	0.114	0.120
Ш	1.20	1.30	1.40	0.047	0.051	0.055
е	1.78	1.90	2.04	0.070	0.075	0.081
L	0.10	0.20	0.30	0.004	0.008	0.012
L1	0.35	0.54	0.69	0.014	0.021	0.029
ΗE	2.10	2.40	2.64	0.083	0.094	0.104
θ	0°		10°	0°		10°

STYLE 6: PIN 1. BASE 2. EMITTER 3. COLLECTOR

### SOLDERING FOOTPRINT\*



\*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

**ON Semiconductor** and **W** are registered trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of SCILLC's product/patent coverage may be accessed at www.onsemic.com/site/pdf/Patent-Marking.pdf. SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typical" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components instended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death massociated with such unintended or unauthorized applicable copyright as medianal second with such unintended or unauthorized polyreable copyright as and leage in any manner.

#### PUBLICATION ORDERING INFORMATION

#### LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor P.O. Box 5163, Denver, Colorado 80217 USA Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada Email: orderlit@onsemi.com N. American Technical Support: 800–282–9855 Toll Free USA/Canada Europe, Middle East and Africa Technical Support:

Phone: 421 33 790 2910 Japan Customer Focus Center Phone: 81–3–5817–1050 ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative